

ECTHCAG12VUH

High Power TVS Diode

The ECTHCAG12VUH is a high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The ECTHCAG12VUH Series complies with the IEC 610002 (ESD) standard with ±30kV air and ±30kV contact discharge. It is assembled into a 3pin DFN2020-3 package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multimedia card interfaces.

Features

- Protects one I/O lines
- Working voltages :12V
- Low leakage current
- Response Time is < 1 ns
- Meets MSL 1 Requirements
- Solid-state silicon avalanche technology
- ROHS compliant



DFN2020-3L

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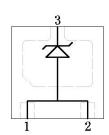
Main applications

- Power Management
- Industrial Application
- Power Supply Protection

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Protection solution to meet

- IEC61000-4-2 (ESD) ± 30 kV (air), ± 30 kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)



Ordering Information

Device	Mark	Qty per Reel	Reel Size
ECTHCAG12VUH	12P/12H	3000	7 Inch

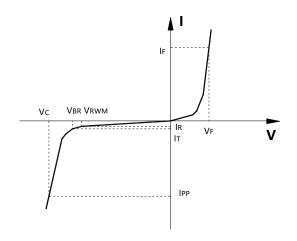


Maximum ratings (Temp=25℃ Unless Otherwise Specified)				
Parameter	Symbol	Value	Unit	
ESD Rating per IEC61000-4-2: Contact		30	1737	
Air		30	KV	
Lead Soldering Temperature	$T_{\rm L}$	260 (10 sec.)	${\mathbb C}$	
Operating Temperature Range	Tı	- 55 ∼ 150	${\mathbb C}$	
Storage Temperature Range	Tstg	- 55 ∼ 150	$^{\circ}$	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Non-repetitive current pulse, per Figure 1.

Symbol	Parameter		
Vrwm	Working Peak Reverse Voltage		
VBR	Breakdown Voltage @ IT		
V _C	Clamping Voltage @ IPP		
I_T	Test Current		
Irm	Leakage current at VRWM		
Ірр	Peak pulse current		
Co	Off-state Capacitance		
C _J	Junction Capacitance		



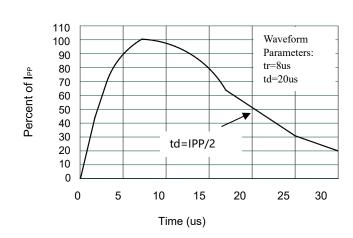
Electrical characteristics (Temp=25°C Unless Otherwise Specified)						
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{RWM}	Reverse Working Voltage	Pin 3 to pin 1,2			12	V
V _{BR}	Reverse Breakdown Voltage	IT = 1 mA,	13.5			V
VBR Rev	Reverse breakdown vonage	Pin 3 to pin 1,2	13.3			
Ir	Reverse Leakage Current	$V_{RWM} = 12V$,			1	1 μΑ
IR Reverse L	Reverse Leakage Current	Pin 3 to pin 1,2			1	
		$I_{PP} = 50A$, $tp = 8/20 \mu s$,		18.8		V
Vc Clamping Volt	Clammin a Valta aa	Pin 3 to pin 1,2		10.0		v
	Clamping voltage	$I_{PP} = 170A$, $tp = 8/20 \mu s$,		24.5	28.5	V
		Pin 3 to pin 1,2	24.	24.3	28.3	
C _J Ju	Innation Compaitons	$V_R = 0V$, $f = 1MHz$,		1.3		nF
	Junction Capacitance	Pin 3 to pin 1,2				
Ірр	Peak Pulse Current	tp=8/20μs waveform			190	A
P_{pp}	Peak Pulse Power	tp=8/20μs waveform		4500		W

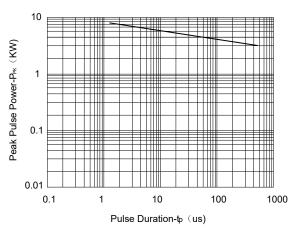
www.ecore-union.com 2 Rev2.0

^{*}Other voltages may be available upon request.



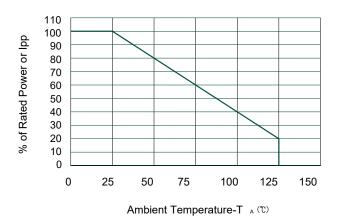
Typical electrical characterist applications





Pulse Waveform

Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve



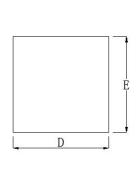
Package Information

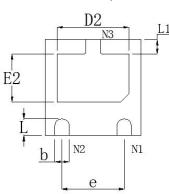
DFN2020-3L

Mechanical Data

Case:DFN2020

Case Material: Molded Plastic. UL Flammability







DIM	Millimeters			
DIM	Min	Nom	Max	
A	0.50	0.55	0.60	
A1	0.00	-	0.05	
А3	0. 15 REF.			
D	1. 95	2.00	2.05	
Е	1. 95	2.00	2.05	
b	0. 25	0.30	0. 35	
L	0.30	0.35	0.40	
L1	0. 25	0.30	0.35	
D2	1.35	1. 50	1.60	
E2	0.85	1.00	1. 10	
е	1.	30 BS0		

Recommended Pad outline

